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(54) Title: **METHOD AND DEVICE FOR IMMERSION LITHOGRAPHY**

(57) Abstract: The present invention relates to an immersion lithographic system for patterning a workpiece arranged at an image plane and covered at least partly with a layer sensitive to electromagnetic radiation. Said system comprising a source emitting electromagnetic radiation onto an object plane, a mask adapted to receive and modulate said electromagnetic radiation at said object plane and to relay said electromagnetic radiation toward said workpiece, and an immersion medium contacting at least a portion of a final lens of said lithographic system and a portion of said workpiece, wherein an area of said contacting is restricted by capillary forces. The invention further relates to a method for patterning a workpiece and a immersion lens as such.

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## METHOD AND DEVICE FOR IMMERSION LITHOGRAPHY

### TECHNICAL FIELD

The present invention relates in general to techniques for optical lithography, and in particular to a method for patterning a workpiece using immersion lithography.

### DESCRIPTION OF THE BACKGROUND ART

When making a pattern on a workpiece, which workpiece could be integrated circuits, masks, reticles, flat panel displays, micro mechanical or micro optical devices and packaging devices, e.g. lead frames and MCM's, a pattern may be exposed in a positive photo resist. In case of producing a mask, the resist in the exposed areas is removed by a develop-and-etch process and, unprotected chromium is then dissolved by a chromium etchant. The result, a glass plate with a pattern in opaque chromium, is used as an optical contact or projection mask for production of a device layer pattern in flat panel displays or integrated circuits.

The pattern generator could be any one of the types of commercially available laser pattern generators using acousto-optical modulators, rotating mirrors and electro-optic shutters, or spatial light modulators for producing said pattern. That is, the light may be scanned or imaged onto the workpiece.

Mask making for the 70nm semiconductor technology node and below is expected to be accomplished by using either electron beam tools or optical mask makers, which employ light with wavelengths shorter than 248nm. Optical mask making tools typically use excimer lasers as their light source, and are therefore restricted in the wavelengths they can use. Krypton

fluoride excimer lasers produce light at 248nm, and the next shorter wavelength available is 193nm, produced by argon fluoride lasers. Adapting optical mask makers to use 193nm is quite difficult for several reasons: (1) the choice of optical materials is restricted, because most optical material absorb 193nm light. Only fused silica and calcium fluoride are commonly used. Optical coatings also present challenges. (2) 193nm light is absorbed by oxygen in the air, with the accompanying production of ozone, so an optical path must be sealed and purged of oxygen. This makes the opto-mechanical design more cumbersome, and makes alignment and measurement quite difficult. (3) 193nm lasers are not as reliable or stable as 248nm lasers, and their energy output is not as large as 248nm lasers, so obtaining and controlling the needed exposure energy becomes problematic. (4) 193nm photons are very energetic, and tend to cause deterioration of materials they strike.

A suitably designed system using immersion optics operating at 248nm is almost certainly capable of achieving lithographic specifications suitable for said 70nm semiconductor technology node, and for the reasons stated above, this may present an easier technological challenge than development of a tool employing shorter wavelengths.

#### SUMMARY OF THE INVENTION

In view of the foregoing background, as the lithographic features required on semiconductor masks get smaller, the demands on the precision and resolution of mask making equipment or direct write equipment increase.

Accordingly, it is an object of the present invention to provide a method for patterning a work piece using immersion lithography, which overcomes or at least reduces the above mentioned problem.

In one embodiment, the invention provides an immersion lithographic system for patterning a work piece arranged at an image plane and covered at least partly with a layer sensitive to electromagnetic radiation. Said lithography system comprising a source emitting electromagnetic radiation onto an object plane, a modulator adapted to receive and modulate said electromagnetic radiation at said object plane in accordance to an input pattern description and to relay said electromagnetic radiation toward said work piece, an immersion medium contacting at least a portion of a objective lens of said lithographic system and a portion of said work piece, wherein an area of said contacting is restricted by capillary forces. Other aspects of the present invention are reflected in the detailed description, figures and claims.

#### BRIEF DESCRIPTION OF THE DRAWINGS

For a more complete understanding of the present invention, and the advantages thereof, reference is now made to the following description taken in conjunction with the accompanying drawings, in which:

Fig. 1 illustrates a schematic view of an embodiment of a pattern generator according to prior art.

Fig. 2a depicts an embodiment of immersion optics according to the present invention.

Fig. 2b depicts an exaggerated view of the encircled area in fig. 2a.

Fig. 3 depicts a plan view of the immersion optics in figure 2b.

Figure 4a-c depict different views of one embodiment of an immersion lens.

Figure 5 depicts a perspective view of the immersion lens as illustrated in figure 4a-c together with a partly shown holder for the same and surrounding features.

#### DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

Figure 1 illustrates an embodiment of an apparatus 100 for patterning a work piece 60 according to prior art, into which the present invention could easily be inserted.

Said apparatus 100 comprising a source 10 for emitting electromagnetic radiation, an objective lens arrangement 50, a computer-controlled reticle 30, a beam conditioning arrangement 20, a spatial filter 70 in a fourier plane, a Fourier lens arrangement 40 and said work piece 60.

The source 10 may emit radiation in the range of wavelengths from infrared (IR), which is defined as 780 nm up to about 20  $\mu\text{m}$ , to extreme ultraviolet (EUV), which in this application is defined as the range from 100nm and down as far as the radiation is possible to be treated as electromagnetic radiation, i.e. reflected and focused by optical components. The source 10 emits radiation either pulsed or continuously. The emitted radiation from the continuous radiation source 10 can be formed into a pulsed radiation by means of a shutter located in the radiation path between said radiation source 10 and said computer-controlled reticle 30. For example, the radiation source may be a KrF excimer laser with a pulsed output at 248 nm, a pulse length of approximately 10 ns and a repetition rate of 1000 Hz. The repetition rate may be below or above 1000 Hz. The beam conditioning arrangement 20 may be a simple lens or an assembly of lenses. The beam conditioning arrangement 20

distributes the radiation emitted from the radiation source 10 uniformly over a surface of the computer-controlled reticle 30. In case of a continuous radiation source a beam of such a source may be scanned over the surface of the computer-controlled reticle.

Workpiece 60 is moved in a systematic fashion so that the optical system synthesizes the desired device layer pattern.

The computer-controlled reticle 30 may be a Spatial Light Modulator (SLM). In this embodiment the SLM comprises all information at a single moment that is required to pattern a certain area of the workpiece 60.

For the remainder of this application an electrostatically controlled micro mirror matrix (one- or two dimensional) is assumed, although other arrangements as described above are possible, such as transmissive or reflective SLMs relying on LCD crystals or electrooptical materials as their modulation mechanism, or micromechanical SLMs using piezoelectric or electrostrictive actuation.

The SLM 30 is a programmable device that produces an output radiation beam that is modulated by separate inputs from a computer. The SLM 30 simulates the function of a mask through the generation of bright and dark pixels in response to computer fed data. For example the phase SLM 30 is an array of etched solid state mirrors. Each micromirror element is suspended above a silicon substrate by restoring hinges, which may be supported either by separate support posts or by the adjacent mirrors. Beneath the micromirror element are address electrodes. One micromirror represents one pixel in the object plane. The pixel in the image plane is here defined as to have the same geometry as the micromirror but the size may be different due to the

optics, i.e. larger or smaller depending on whether the optics is magnifying or demagnifying.

The micromirror and the address electrodes act as a capacitor so that for example a negative voltage applied to the micromirror, along with a positive voltage to the address electrode, will twist the torsion hinges suspending the micromirror which in turn allow the micromirror to rotate or to move up or down, thereby creating a phase modulation of the reflected light.

A projection system comprises in this embodiment the Fourier lens arrangement 40, which may be a compounded tube lens, the spatial filter 70 and the objective lens arrangement 50. The Fourier lens arrangement 40 and the spatial filter 70 form together what is generally called a Fourier filter. The Fourier lens arrangement 40 projects the diffraction pattern onto the spatial filter 70. The objective lens arrangement 50, which may be a compounded final lens, forms the aerial image on the work piece 60.

The spatial filter 70 is in this embodiment an aperture in a plate. Said aperture being sized and positioned so as to block out essentially all light which is diffracted into the first and higher diffraction orders, for example said aperture may be located at the focal distance from the Fourier lens arrangement 40. The reflected radiation is collected by said Fourier lens arrangement 40 in the focal plane, which acts at the same time as a pupil plane of the objective lens arrangement 50. The aperture cuts out the light from the first and higher diffraction orders of the addressed micromirrors in the SLM, while the radiation from the non-addressed mirror surfaces can pass the aperture. The result is an intensity modulated aerial image on the work piece 60 as in conventional lithography.

Figure 2a illustrates immersion optics 200 according to one embodiment of the present invention. An exaggerated view is illustrated in figure 2b of the encircled area in figure 2a. In figure 2a, a workpiece is denoted 260 and an objective lens denoted 250. The objective lens 50 in figure 1 is separated from the workpiece by air or any other gaseous medium. In figure 2a and 2b the objective lens 250 is in contact with the workpiece 260 via an immersion medium, normally a liquid.

In the exaggerated view in figure 2b the details of the objective lens 250 and its surrounding elements are denoted as follows, an immersion fluid supply tube 230, an immersion fluid reservoir 210, a last element of the objective lens 220, dispenser grooves 290, 291, replaceable flat cover glass 292, immersion fluid film 294, a porous element 215, immersion fluid level 232, fluid removal tube 240, drying air 252, focus air 280, and the workpiece 260.

The immersion fluid may be any fluid, which will not react adversely with a photolithographic resist on the work piece, i.e., dissolve the resist or contaminate the same, is sufficiently transparent to the radiation in use, has an index of refraction such as to permit improved resolution imaging onto the resist etc. An example of such fluid is purified water.

Immersion fluid is supplied to the immersion fluid reservoir 210 via immersion fluid supply tube 230. The immersion fluid level 232 in the first immersion fluid reservoir 210 is kept on a level such that the porous or fibrous material 215 is partially saturated with said immersion fluid, here said partial saturation is indicated by a immersion fluid level 232 that is below a highest point of the porous material 215.



The immersion fluid is removed away from the fluid reservoir 210 via the immersion fluid removal pipe 240. Said fluid reservoir may be connectable to said porous material.

The porous material can be said to have several properties and functionality.

Firstly, said porous material may prohibit or substantially reduce said immersion liquid to comprise air or gaseous bubbles. Air or gaseous bubbles will cause undesired optical phenomena on the workpiece.

Secondly, when the immersion optics 200 will reach an edge of the workpiece to be patterned there will be no spill of immersion fluid since the porous material will suck up said immersion fluid from the surface. This is possible since said porous material is not completely saturated with said immersion liquid.

The distance from the last element of the final lens and the work piece is kept at a constant level by an air gage and a servo control (not shown). Focus air 280 is supplied into the substrate via at least one orifice 282 and for instance a hot wire will refer its temperature to another hot wire. Said another hot wire is set up to the desired conditions and any deviations between the two may be adjusted by lowering or increasing the focus air supply. Other air gage mechanism will be obvious for one skilled in the art and therefore needs no further explanation here.

Drying air 252 may be optionally supplied to the workpiece in order to eliminate any immersion fluid film remaining on the moving workpiece, which may affect the measuring of the distance via said air gage. Therefore said drying air is

supplied to the wafer before the focus air, i.e., in between the immersion fluid film and the focus air.

Dispenser grooves 290, 291 are optionally arranged in the immersion optics 200. Said dispenser grooves have the property of supplying said immersion medium to a homogenous film between the objective lens and said workpiece more efficiently than without said grooves.

Said porous material may be a ceramic material, a wick or fibrous material, any suitable sintered material or an artificially manufactured honeycomb structure. It is also possible to use a solid material in which a plurality of holes are made. A dimension of said holes are adapted to exhibit a desired capillary action.

The objective lens may optionally be covered with said replaceable flat cover glass 292. Said glass will prevent said objective lens from any damage while scanning the objective lens over the workpiece 260.

The distance between the objective lens and the work piece may be between 200nm to 1mm.

In another embodiment said porous material 215 is omitted. Immersion medium is then supplied via at least one orifice to the gap between said immersion optics 200 and said work piece 260. The immersion is likewise removed through at least one orifice connectable to said immersion fluid reservoir and said immersion fluid removal tube.

The supply of immersion medium maintains the lateral dimension and homogeneity of the immersion film between the immersion optics and the work piece.

In the embodiment illustrated in figure 2b the immersion medium film is cut at the curved surface 295. At this curved surface the capillary action is gradually reduced, and the immersion medium will stop to expand when a certain distance between the immersion optics 200 and the work piece 260 is reached. This design efficiently keeps control of the lateral extension of the immersion medium film.

The immersion fluid or medium supply makes sure that there is always enough immersion fluid to use. When the work piece is scanned in a lithographic process there is always some loss of immersion medium due to adhesion to the surface of the workpiece and/or evaporation. After a certain time there will be too little immersion medium for creating a homogenous film. At such time air bubbles may be created and the lithographic imaging process will be destroyed. Or, insufficient exchange of immersion medium may allow contaminants produced during exposure to accumulate and alter the properties of the immersion film

Figure 3 illustrates a plan view of the immersion optics 200 in figure 2a. The last (lowest) element 220 of the objective lens 250 is located in the middle of the immersion optics 200. The porous material 215 is surrounding said objective lens element. The immersion medium is supplied through the immersion medium supply tube 230 and removed from the immersion medium removal tube 240. Focus air 280 is used to keep control of the distance between the work piece and the objective lens.

In another embodiment at least a portion of the surface of said immersion optics, which is in contact with said immersion medium, has the property of wetting said surface, which in case of using water is denoted by hydrophilic properties. The workpiece, or more correctly the surface of the resist layer has non-wetting properties, which in the case of using water is

denoted hydrophobic properties. This arrangement will make sure that there the immersion objective is always in contact with said immersion medium. The hydrophobic properties of the resist may reduce the immersion medium loss during scanning.

Figure 4a-c illustrates an embodiment of an immersion lens 400 according to the present invention. Figure 4a is a bottom view of said immersion lens 400, figure 4b is a side view of said immersion lens 400 and figure 4c is a cross section of said immersion lens 400 along A-A as indicated in figure 4b.

Said inventive immersion lens comprises a flange surface 412, a protrusion 402, a first orifice 404, a second orifice 406, a first connection pipe 408, a second connecting pipe 410. Said flange surface is used to fix said immersion lens to a support structure, partly shown and depicted by reference numeral 550 in figure 5. Said first and second connecting pipes have an inlet 408a and an outlet 408b. Said protrusion comprising said first and second orifices. Said first orifice 404 may be an immersion medium inlet orifice and said second orifice may be an immersion medium removal orifice. Said immersion medium removal orifice and said immersion medium inlet orifice are reversible, i.e., when said workpiece is moved in a first direction relative to said immersion lens 400, said first orifice 404 may be said immersion medium inlet orifice and said second orifice 406 may be said immersion medium removal orifice. When the workpiece is moved in a second direction, opposite to the first direction, relative to the immersion lens said first orifice 404 may be said immersion medium removal orifice and said second orifice 406 may be said immersion medium inlet orifice.

The first and second orifices are provided in a line, which essentially coincides with the direction of movement of the workpiece relative to the immersion lens. When said workpiece

is moving in a direction from said first orifice 404 to said second orifice 406, said first orifice 404 may be said immersion medium inlet orifice and said second orifice 406 is said immersion medium removal orifice. When said workpiece is moving in a direction from said second orifice 406 to said first orifice 404, said second orifice 406 may be said immersion medium inlet orifice and said first orifice 404 may be said immersion medium removal orifice.

Figure 5 depicts the inventive immersion lens 400 together with a support structure 550, which is only partly shown. Said support structure 550 comprising a first air focus orifice 502, a second air focus orifice 504, said immersion lens 400, a first immersion medium removal device 506 and a second immersion medium removal device 507. Said first and second immersion medium removal devices 506 and 507 respectively comprise outlet orifices 508 and 509 respectively.

The protrusion 402 may essentially be of the same height from the workpiece as the first and second immersion removal devices 506 and 507 respectively. Any immersion medium, which may come loose from a film between said protrusion 402 and said workpiece, essentially restricted in lateral direction by capillary forces, is captured by either said first or second immersion medium removal device 506 or 507 respectively, which one used is depending on the direction of movement of the workpiece relative to said immersion lens 400. Said immersion medium removal device is horse shoe formed to make sure that no immersion medium is coming beneath said first or second air focus orifice 502 and/or 504, i.e., a barrier is formed between the air focus orifice and a possible direction of any loosened immersion medium. Said air focus orifice may be connected to a control unit and a reference unit in conventional known manner in order to measure the distance between the immersion lens and

the workpiece. This technique is well known to a person skilled in the art and therefore needs no further explanation.

Thus, although there has been disclosed to this point a particular embodiment of the apparatus for patterning a work piece, it is not intended that such specific reference be considered as limitations upon the scope of this invention except in-so-far as set forth in the following claims.

For instance instead of using at least one spatial light modulator for generating the desired pattern to be printed on said work piece, acoustooptical devices (modulators and deflectors) may be used for the same purpose. Such devices are used in commercially available laser scanners for use in laser lithography, for instance Micronic's own Omega machines. Another pattern generator which uses acousto optical modulators and a rotating prism is Applied materials Alta machines. It is also possible to use a mask or a reticle for generating the pattern, i.e., a stepper.

Furthermore, having described the invention in connection with certain specific embodiment thereof, it is to be understood that further modifications may suggest themselves to those skilled in the art, it is intended to cover all such modifications as fall within the scope of the appended claims.

## CLAIMS

1. An immersion lithographic system for patterning a work piece arranged at an image plane and covered at least partly with a layer sensitive to electromagnetic radiation, comprising:
  - a source emitting electromagnetic radiation onto an object plane,
  - a modulator, adapted to receive and modulate said electromagnetic radiation at said object plane in accordance to an input pattern description, and to relay said electromagnetic radiation toward said work piece,
  - an immersion medium contacting at least a portion of an immersion optics of said lithographic system and a portion of said work piece, wherein said immersion medium is supplied through at least one orifice arranged in said immersion optics.
2. The apparatus according to claim 1, wherein said modulator is an SLM.
3. The apparatus according to claim 2, wherein said SLM comprises reflective pixels.
4. The apparatus according to claim 3, wherein said reflective pixels are micromirrors.
5. The apparatus according to claim 1, wherein said modulator is an acoustooptical modulator.
6. The apparatus according to claim 1, wherein said source emitting electromagnetic radiation is an excimer laser.

7. The apparatus according to claim 1, further comprising a porous or fibrous material through which said immersion medium is supplied.
8. The apparatus according to claim 1, further comprising at least one immersion medium removal orifice.
9. The apparatus according to claim 8, further comprising a porous or fibrous material through which said immersion medium is removed.
10. The apparatus according to claim 7 or 9, wherein said at porous material is kept incompletely saturated with said immersion medium.
11. An immersion lithographic system for patterning a work piece arranged at an image plane and covered at least partly with a layer sensitive to electromagnetic radiation, comprising
  - a source emitting electromagnetic radiation onto an object plane,
  - a mask arranged at said object plane to relay said electromagnetic radiation toward said work piece,
  - an immersion medium contacting at least a portion of an immersion optics of said lithographic system and a portion of said work piece, wherein said immersion medium is supplied through at least one orifice arranged in said immersion optics.
12. The apparatus according to claim 11, wherein said source emitting electromagnetic radiation is an excimer laser.
13. The apparatus according to claim 11, further comprising a porous or fibrous material through which said immersion medium is supplied.



14. The apparatus according to claim 11, further comprising at least one immersion medium removal orifice.
15. The apparatus according to claim 14, further comprising a porous or fibrous material through which said immersion medium is removed.
16. The apparatus according to claim 13 or 15, wherein said at porous or fibrous material is kept incompletely saturated with said immersion medium.
17. An immersion lithographic system for patterning a work piece arranged at an image plane and covered at least partly with a layer sensitive to electromagnetic radiation, comprising
- a source emitting electromagnetic radiation onto an object plane,
  - a modulator, adapted to receive and modulate said electromagnetic radiation at said object plane in accordance to an input pattern description and to relay said electromagnetic radiation toward said work piece,
  - an immersion medium contacting at least a portion of a objective lens of said lithographic system and a portion of said work piece, wherein an area of said contacting is restricted by capillary forces.
18. The immersion lithography system according to claim 17, further comprising a immersion medium reservoir for supplying immersion medium to said portion of said objective lens and said workpiece.
19. The immersion lithography system according to claim 18, wherein said immersion medium is supplied through a porous or fibrous material.

20. An immersion lithographic system for patterning a work piece arranged at an image plane and covered at least partly with a layer sensitive to electromagnetic radiation, comprising
- a source emitting electromagnetic radiation onto an object plane,
  - a mask, adapted to receive and modulate said electromagnetic radiation at said object plane and to relay said electromagnetic radiation toward said work piece,
  - an immersion medium contacting at least a portion of a final lens of said lithographic system and a portion of said work piece, wherein an area of said contacting is restricted by capillary forces.
21. The immersion lithography system according to claim 17, further comprising a immersion medium reservoir for supplying immersion medium to said portion of said objective lens and said workpiece.
22. The immersion lithography system according to claim 18, wherein said immersion medium is supplied through a porous or fibrous material.
23. A method for patterning a workpiece arranged at an image plane and covered at least partly with a layer sensitive to electromagnetic radiation, including the actions of:
- emitting electromagnetic radiation onto an object plane,
  - modulating said electromagnetic radiation at said object plane in accordance to an input pattern description,
  - relaying said electromagnetic radiation toward said workpiece,

- supplying an immersion medium to contact at least a portion of an objective lens of said lithographic system and at least a portion of said workpiece.

24. The method according to claim 23, further comprising the action of:

- restricting a lateral extension of said contact by capillary forces.

25. A method for patterning a workpiece arranged at an image plane and covered at least partly with a layer sensitive to electromagnetic radiation, including the actions of:

- emitting electromagnetic radiation onto an object plane,
- modulating said electromagnetic radiation at said object plane in accordance to an input pattern description,
- relaying said electromagnetic radiation toward said workpiece,
- contacting at least a portion of an objective lens of said lithographic system and at least a portion of said workpiece via a immersion medium, wherein said contacting is restricted in a lateral direction of said workpiece by capillary forces.

26. The method according to claim 25, further including the action of:

- supplying said immersion medium via a immersion medium reservoir.

27. The method according to claim 26, wherein said immersion medium is supplied through a porous or fibrous material.

28. A method for patterning a workpiece arranged at an image plane and covered at least partly with a layer sensitive to electromagnetic radiation, including the actions of:

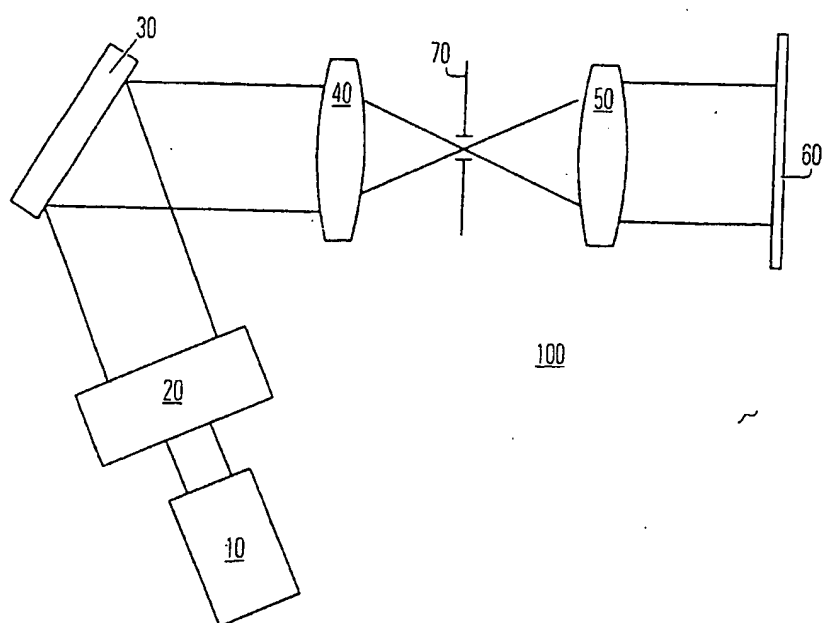
- emitting electromagnetic radiation onto an object plane,
- modulating said electromagnetic radiation at said object plane in accordance to an input pattern description,
- relaying said electromagnetic radiation toward said workpiece,
- forming an immersion medium film to contact at least a portion of an objective lens of said lithographic system and at least a portion of said workpiece,
- supplying immersion medium to said immersion medium film to maintain its lateral dimensions while moving said objective lens over said workpiece.

29. An immersion lens (400) for use in a lithographic apparatus and to be contactable to a workpiece via an immersion medium, said immersion lens (400) including at least one immersion medium inlet orifice, at least one immersion medium removal orifice and at least one protrusion (402), said at least one immersion medium inlet orifice and said at least one immersion medium removal orifice are formed in said protrusion (402), which is directed towards said workpiece.

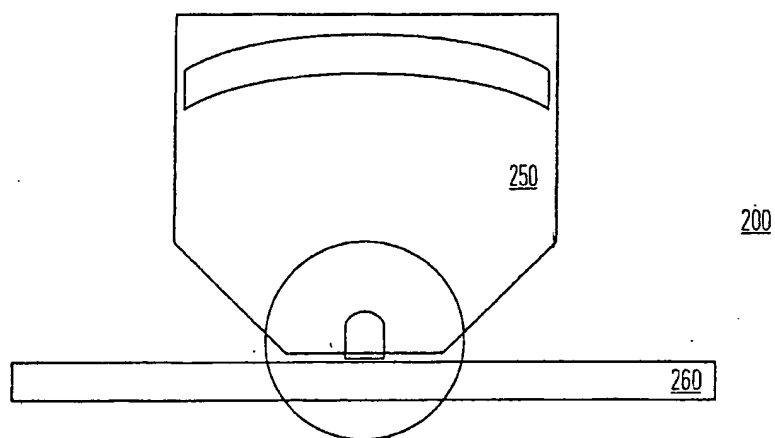
30. The immersion lens (400) according to claim 29, wherein said immersion medium inlet orifice and said immersion medium removal orifice are reversible in dependence of the direction of movement of said immersion lens (400) relative to said workpiece.

31. The immersion lens (400) according to claim 29, wherein said immersion medium is restricted to the area beneath said protrusion (402) by means of capillary forces.

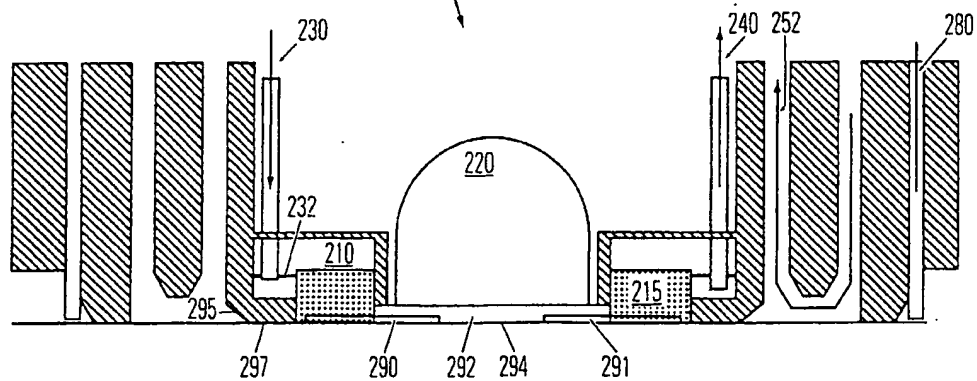
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**FIG. 1**



**FIG. 2A**



**FIG. 2B**

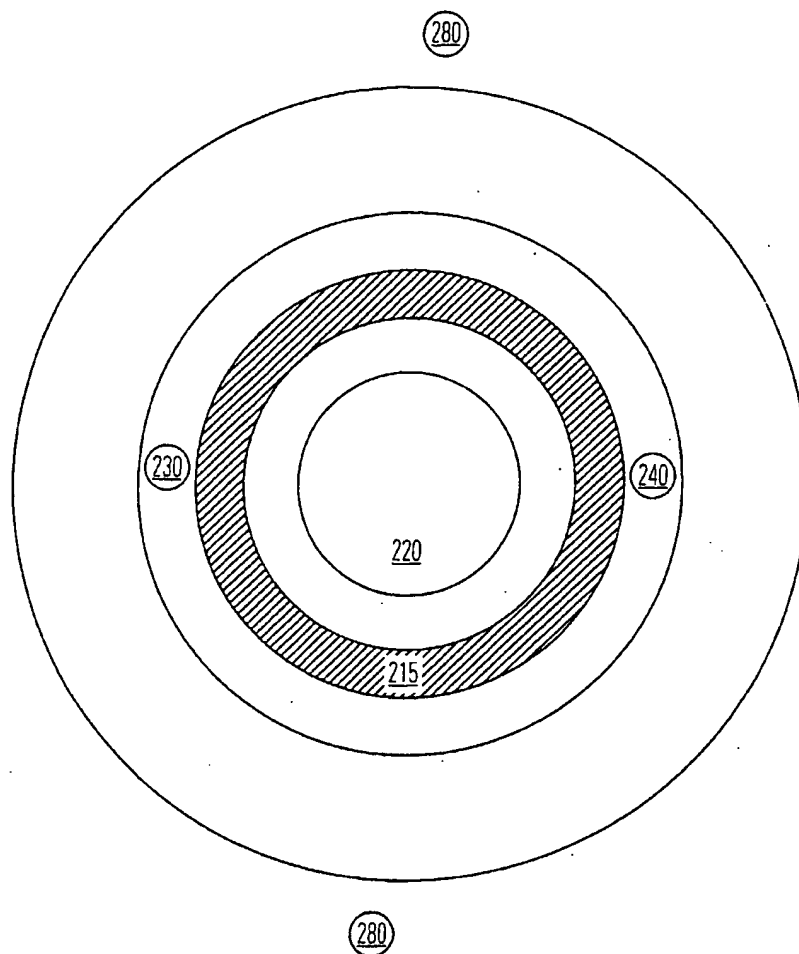


FIG. 3

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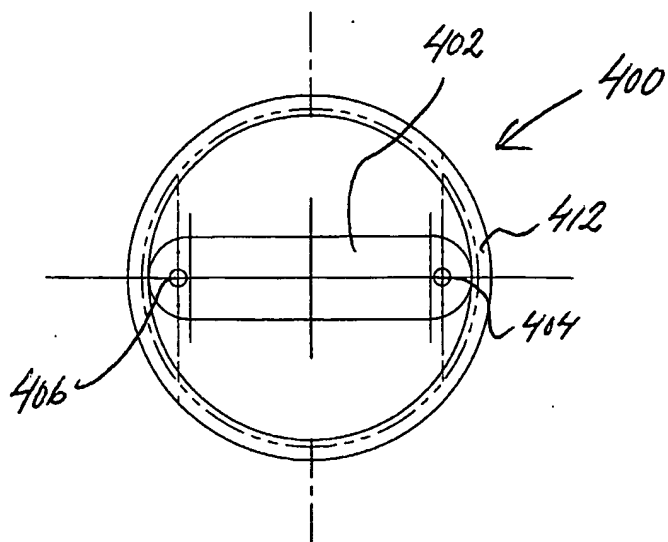


Fig. 4a

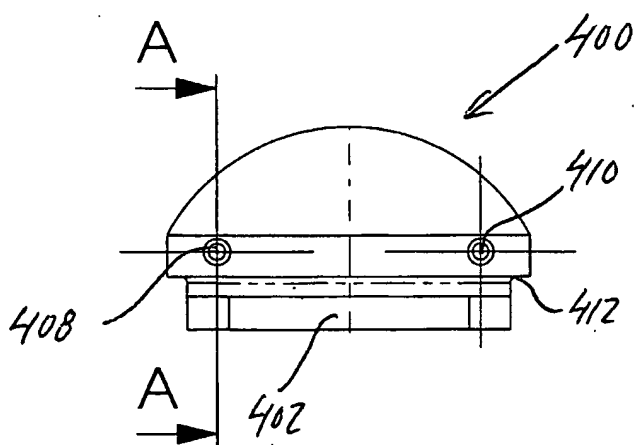


Fig. 4b

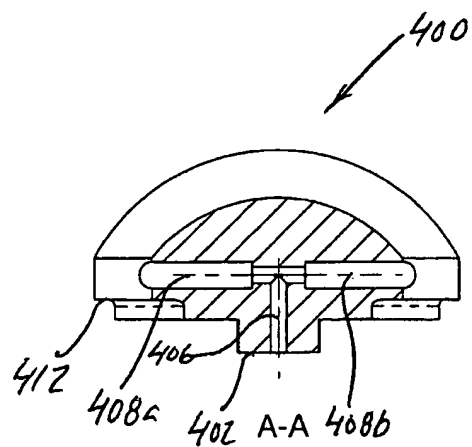


Fig. 4c



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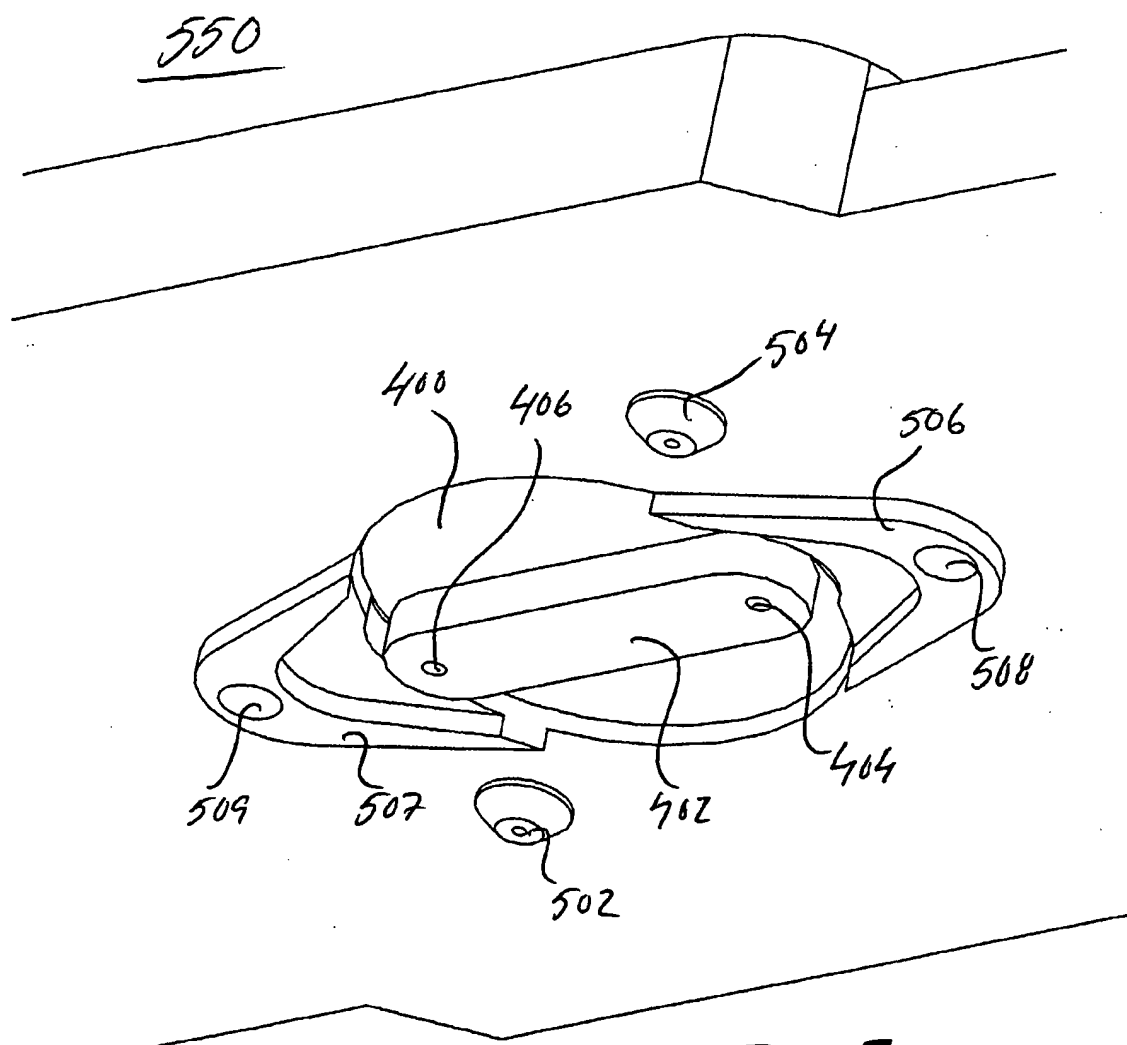


Fig. 5

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AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW.

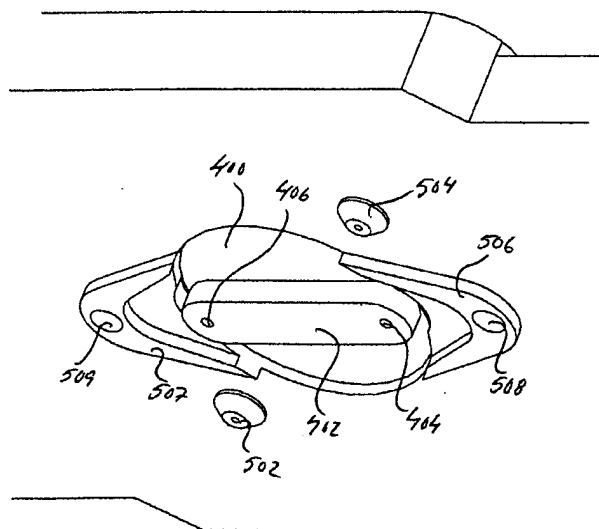
(84) Designated States (unless otherwise indicated, for every kind of regional protection available): ARIPO (BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

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For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: **METHOD AND DEVICE FOR IMMERSION LITHOGRAPHY**



(57) Abstract: The present invention relates to an immersion lithographic system for patterning a workpiece arranged at an image plane and covered at least partly with a layer sensitive to electromagnetic radiation. Said system comprising a source emitting electromagnetic radiation onto an object plane, a mask adapted to receive and modulate said electromagnetic radiation at said object plane and to relay said electromagnetic radiation toward said workpiece, and an immersion medium contacting at least a portion of a final lens of said lithographic system and a portion of said workpiece, wherein an area of said contacting is restricted by capillary forces. The invention further relates to a method for patterning a workpiece and a immersion lens as such.

WO 2005/034174 A3

## INTERNATIONAL SEARCH REPORT

International application No.

PCT/SE 2004/001403

## A. CLASSIFICATION OF SUBJECT MATTER

IPC7: G03F 7/20

According to International Patent Classification (IPC) or to both national classification and IPC

## B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

IPC7: G03F

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

SE,DK,FI,NO classes as above

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

EPO-INTERNAL, WPI, PAJ

## C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	US 4480910 A (A.TAKANASHI ET AL), 6 November 1984 (06.11.1984), figure 3	1-8,11-14, 23-24,28-29, 31
Y		17-18,20-21, 25-26
A		9,10,15,16, 19,22,27,30
	--	
X	US 20030030916 A1 (Y.SUENAGA), 13 February 2003 (13.02.2003), part(0051)	1-8,11-14, 17-18,20-21, 23-26,28-29, 31
	--	

☒ Further documents are listed in the continuation of Box C.

☒ See patent family annex.

\* Special categories of cited documents:

"A" document defining the general state of the art which is not considered to be of particular relevance

"E" earlier application or patent but published on or after the international filing date

"L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)

"O" document referring to an oral disclosure, use, exhibition or other means

"P" document published prior to the international filing date but later than the priority date claimed

"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention

"X" document of particular relevance: the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone

"Y" document of particular relevance: the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art

"&amp;" document member of the same patent family

Date of the actual completion of the international search

7 March 2005

Date of mailing of the international search report

08-03-2005

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## INTERNATIONAL SEARCH REPORT

International application No.

PCT/SE 2004/001403

C (Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT		
Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	US 5900354 A (J.S.BATCHELDER), 4 May 1999 (04.05.1999), column 2, line 31, figure 4  --	1-8,11-14, 17-18,20-21, 23-26,28-29, 31
X	JP 10255319 A (HITACHI MAXELL LTD), 25 Sept 1998 (25.09.1998), figure 6  --	1,11,29
Y	US 6230722 B1 (K.MITSUMORI ET AL), 15 May 2001 (15.05.2001), figure 1  --	17-18,20-21, 25-26
X	WO 9949504 A1 (NIKON CORPORATION), 30 Sept 1999 (30.09.1999), figure 1, abstract  --	1,11,17,23, 25,28
E	EP 1498778 A1 (ASML NETHERLANDS B.V.), 19 January 2005 (19.01.2005), part [0016]-[0023]  -- -----	1-31

# INTERNATIONAL SEARCH REPORT

International application No.

## Box No. II Observations where certain claims were found unsearchable (Continuation of item 2 of first sheet)

This international search report has not been established in respect of certain claims under Article 17(2)(a) for the following reasons:

1. ☐ Claims Nos.:  
because they relate to subject matter not required to be searched by this Authority, namely:
  
2. ☐ Claims Nos.:  
because they relate to parts of the international application that do not comply with the prescribed requirements to such an extent that no meaningful international search can be carried out, specifically:
  
3. ☐ Claims Nos.:  
because they are dependent claims and are not drafted in accordance with the second and third sentences of Rule 6.4(a).

## Box No. III Observations where unity of invention is lacking (Continuation of item 3 of first sheet)

This International Searching Authority found multiple inventions in this international application, as follows:

See extra sheet

1. ☐ As all required additional search fees were timely paid by the applicant, this international search report covers all searchable claims.
2. ☒ As all searchable claims could be searched without effort justifying an additional fee, this Authority did not invite payment of any additional fee.
3. ☐ As only some of the required additional search fees were timely paid by the applicant, this international search report covers only those claims for which fees were paid, specifically claims Nos.:
  
4. ☐ No required additional search fees were timely paid by the applicant. Consequently, this international search report is restricted to the invention first mentioned in the claims; it is covered by claims Nos.:

### Remark on Protest

- ☐ The additional search fees were accompanied by the applicant's protest.
- ☐ No protest accompanied the payment of additional search fees.

## INTERNATIONAL SEARCH REPORT

International application No.

### Continuation of Box III

The technical relationship among the independent claims, and the only corresponding technical feature of the independent claims, is "an immersion medium contacting an immersion optics and a work piece". Since this feature is known from for instance US4480910 it is not considered as a special technical feature according to Rule 13.2 PCT.

Consequently, *á posteriori*, the application comprises three inventions as follows:

- I. Claims 1-16 and 29-31 directed towards a supply orifice.
- II. Claims 17-22 and 25-27 directed towards capillary forces.
- III. Claims 23-24 and 28 directed towards relaying of the electromagnetic radiation.

The problem solved in each group is alternative solutions.

Neither the problem underlying the subjects of the claimed inventions, nor their solutions defined by the special technical features allow for a relationship to be established between the said inventions, which involves a single general inventive concept.

In conclusion, therefore, the three groups of claims are not linked by same or corresponding special technical features and define different inventions not linked by a single general inventive concept.

The application, hence does not meet the requirements of unity of invention as defined in Rule 13.1 and 13.2 PCT.

However, all searchable claims could be searched without effort justifying an additional fee.

**INTERNATIONAL SEARCH REPORT**  
Information on patent family members

30/01/2005

International application No.

PCT/SE 2004/001403

US	4480910	A	06/11/1984	CA	1159160	A	20/12/1983
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				EP	0060729	A,B	22/09/1982
				JP	1501475	C	28/06/1989
				JP	57150513	U	21/09/1982
				JP	57153433	A	22/09/1982
				JP	63049893	B	06/10/1988
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				US	6633365	B	14/10/2003
				US	6844919	B	18/01/2005
				US	20040021844	A	05/02/2004
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JP	10255319	A	25/09/1998	NONE			
<hr/>							
US	6230722	B1	15/05/2001	JP	11033506	A	09/02/1999
				US	6517635	B	11/02/2003
				US	20010037819	A	08/11/2001
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WO	9949504	A1	30/09/1999	AU	2747999	A	18/10/1999
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EP	1498778	A1	19/01/2005	EP	1494079	A	05/01/2005
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